# **Course Manual RM**

Scanning Microscopy

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#### - General information

Long name	Scanning Microscopy
Approving CModule	<u>RM_MaET</u>
Responsible	Prof. Dr. Stefan Altmeyer Professor Fakultät IME
Valid from	winter semester 2020/21
Level	Master
Semester in the year	winter semester
Duration	Semester
Hours in self-study	114
ECTS	5
Professors	Prof. Dr. Stefan Altmeyer Professor Fakultät IME
Requirements	mathematics: differential- and integral calculus complex numbers vector calculus basics of differential geometry physics / optics: geometrical optics wave optics
Language	German
Separate final exam	Yes

#### Literature

Reimer: Scanning Electron Microscopy (Springer)

Meyer, Hug, Bennewitz: Scanning Probe Microscopy (Springer)

Wilhelm, Gröbler, Gluch, Heinz: Die konfokale Laser Scanning Mikroskopie (Carl Zeiss)

#### **Final exam**

Details

As long as the number of participants is not too high, oral examination is preferred of written exams.

To a small amount, the lowest competence level, knowledge, is checked. This could be e.g. the different types of cathodes in electron microscopes, which lead to different classes of instruments or it could be a question regarding the different building principles of confocal measurement setups.

The next competence level is related to skills.

Examination could be done by showing the sketch of a setup and it has to be devided into different functional groups and the critical aspects in each group has to be identified. Another skill to be tested could be to start from the Lorenz force and show, why charged particles don't change their energy in magnetic fields.

The highest competence level adressed is methodical expertise. It can be checked by the discussion of a real world task: More scientific tasks could be to give a justified explaination, if the construction of an electron microscope with a certain acceleration voltage needs relativistic calculation or not. Another question could be if quantum effects have to be taken into account or not when dealing with a certain type of cathode system. More practical oriented questions could regard a measurement task in 3D topography and it has to be explained, what measurement principle could be chosen for this task and which one not. A guided discussion is very well suited to find out, if the underlying principles are understood and can be applied correctly, if scientific transfer is possible and how much overview there is.

Minimum standard

Correct answer of at least 50 % of the questions

Exam Type

EN mündliche Prüfung, strukturierte Befragung

### - Lecture / Exercises

Goal type	Description
Knowledge	electron microscopy
5	wave-particle dualism of electrons
	De Brogli wavelength
	reletivistic mass increas
	resolution of electron optical
	systems
	depth of field in an electron
	microscope
	electron emission
	physics of electron emission thermoionic emission
	Schottky emission
	field emission
	technical construction of electron
	emitters
	brigthness as a conserving
	magnitude
	magentic deflection units
	focussing lens
	equations of motion for electrons
	in focussing lenses
	principles of aberration
	minimization
	scan system
	electron matter interaction
	primary electrons
	secondary electrons Auger electrons
	Bremsstrahlung
	characteristic x rays
	cathodo luminescence
	Everhart-Thornley detector
	electron contrast
	topography contrast
	material contrast
	lattice orientation contrast
	conductivity contrast
	applications and limitations
	tunneling microscope
	tunneling microscope wave function
	definition
	continuity and continuous
	differentiable
	probability interpretation
	principle
	potential diagram
	Fermi level
	work function
	quantummechanical calculation of
	the turneling probability

the tunneling probability

biased tunneling barrier and WKB

## Special requirements

none

Accompanying	
material	

Separate exam

downloadable file

lecture notes as

	approximation
	piezo motors
	physical principles
	nonlinearity, hysteresis, creep
	principles of control theory in a
	tunneling microscope
	preparation of tunneling tips
	image as result of a measurement
	convolution of object and tip
	lattive resolution and atomic
	resolution
	applications and limits
	atomic force microscope
	setup
	types: contact mode, noncontact
	mode, tapping mode, magnetic
	mode,
	applications and limits
	confocal microscopy
	principle of confocal apertures
	principle of optical sectioning
	lateral and axial resolution
	pupil illumination and over-
	illumination in concofal laser
	scanning microscopes
	problems of adjustment
	Nipkow disc
	freedom of adjustment
	light budget and reflections
	rotating microlens array
	confocal dispersion sensor
	applications and limits
Skills	electron micorscope
	calculate classical and relativistic
	electron speeds
	calculate wavelngths of electron
	calculate resolution of electron
	optical systems
	explain the different emission
	regimes
	explain the different electron-
	matter interaction processes
	sketch and explain the different
	types of electron lenses
	sketch and explain an Everhart-
	Thornley detector
	calculate the depth of field in an
	electron microscope
	tunneling microscope
	sketch and explain the potential
	over space diagram for tunneling
	explain the Ansatz to calculate the
	explain the Ansatz to calculate the
	explain the Ansatz to calculate the tunneling probability
	explain the Ansatz to calculate the tunneling probability explain the difference between
	explain the Ansatz to calculate the tunneling probability explain the difference between

## Expenditure classroom teaching

Т	уре	Attendance (h/Wk.)
	ecture	0
E	xercises (whole course)	0
1	xercises (shared ourse)	0
Т	utorial (voluntary)	0

### - Practical training

- Accompan material Separate e	Description Adjustment and use of	Goal type
material	Adjustment and use of	
material		Skills
material	electron microscopes	
material	tunneling microscopes	
Separate e	atomic force microscopes	
Separate e	confocal micorscopes	
	perform a metrological task	
	measurement of hights	
	measurement of 3D topographies structural analysis	
Separate e	finding ultimate resolution limits	
Exam Type	interpretation of metrological	

#### Expenditure classroom teaching

Туре	Attendance (h/Wk.)
Practical training	2
Tutorial (voluntary)	0

### quirements nying none Yes exam exam EN Projektaufgabe im e Team bearbeiten (z.B. im Praktikum) Details Accopmpaning the execution of the metrological task Examination of the theoretical background regarding the underlying principles of the instrumentation and the application Examination of the results regarding the technical level of the experimental process and the scientific level of the analysis and interpretation. **Minimum standard** All experimentals tasks have been performed. In all experiments a level of understanding is achieved, that a use of the instrumention all alone is possible. At least 50 % of the images and measurement results would be, if given in an industrial or scientific context, regarded as sufficient and problem solved.

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